

Form PTO-1449

INFORMATION DISCLOSURE CITATION  
IN AN APPLICATION

(Use several sheets if necessary)

Docket Number (Optional)

INT-03-014

Application Number

10/827,061

Applicant

Thomas Aisenbrey

Filing Date

04/19/04

Group Art Unit

2821  
EX: CHUCTRAN

## U. S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILED DATE IF APPROPRIATE
TC	61113438	8/29/00	Unami et al.	310	366	8/20/98
TC	4267480	5/12/81	Kanematsu et al.	310	366	5/23/79
TC	4786937	11/22/88	Kalnin et al.	310	364	5/5/87
TC	6664863	12/16/03	Okamoto et al.	331	117R	7/24/00
TC	6268778	7/31/01	Mucke et al.	331	117R	5/3/99

## FOREIGN PATENT DOCUMENTS

DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation YES NO
T.C. 2 377449A	11/15/03	United Kingdom	CO8K	3/08	

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

TC	Cleland et al., "Fabrication of high frequency nanometer scale mechanical resonators from bulk Si crystals", Applied Physics Letter 69(18), 28 Oct. 1996, pp. 2653-2655.
TC	

EXAMINER

DATE CONSIDERED

3/2/06

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.